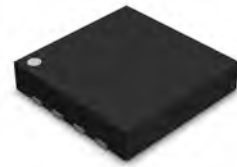


**DFNWB3×3-8L Plastic-Encapsulate MOSFETS****CJAE35P03 P-Channel Power MOSFET**

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-30V	10mΩ@-10V	-35A

DFNWB3×3-8L**DESCRIPTION**

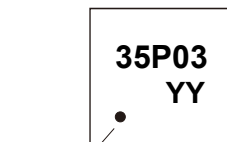
The CJAE35P03 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications

FEATURES

- High density cell design for ultra low $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

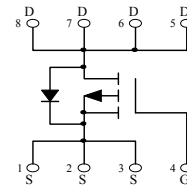
APPLICATIONS

- Battery and loading switching

MARKING

PIN1

35P03 = Part No.
Solid dot=Pin1 indicator.
YY=Code.

EQUIVALENT CIRCUIT**ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D ①	-35	A
Pulsed Drain Current	I_{DM} ②	-140	A
Single Pulsed Avalanche Energy	E_{AS} ③	190	mJ
Power Dissipation	P_D ①	28	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$ ⑥	83.3	°C/W
Thermal Resistance from Junction to Case	$R_{\theta JC}$ ①	4.46	°C/W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	°C

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^{\circ}\text{C}$ unless otherwise specified

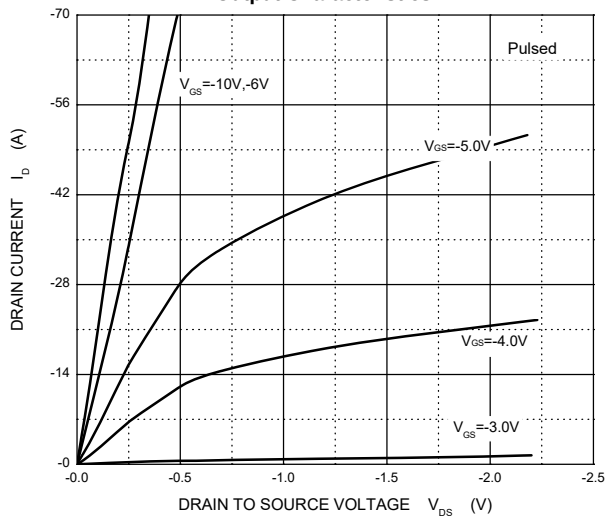
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	-30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -24V, V_{GS} = 0V$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	-1.0	-1.6	-2.5	V
Drain-source on-resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -12A$		10	15	m Ω
		$V_{GS} = -4.5V, I_D = -12A$		15	25	m Ω
Dynamic characteristics ④ ⑤						
Total gate charge	Q_g	$V_{DS} = -15V, V_{GS} = -10V, I_D = -12A$		38		nC
Gate-source charge	Q_{gs}			7		
Gate-drain charge	Q_{gd}			9		
Input Capacitance	C_{iss}	$V_{DS} = -15V, V_{GS} = 0V, f = 1MHz$		2280		pF
Output Capacitance	C_{oss}			385		
Reverse Transfer Capacitance	C_{rss}			278		
SWITCHING PARAMETERS ④ ⑤						
Turn-on delay time	$t_{d(on)}$	$V_{DS} = -15V, I_D = -1A,$ $V_{GS} = -10V, R_G = 2.5\Omega$		10		ns
Turn-on rise time	t_r			22		
Turn-off delay time	$t_{d(off)}$			36		
Turn-off fall time	t_f			9		
Source-Drain Diode characteristics						
Body diode voltage	V_{SD} ④	$I_S = -12A, V_{GS} = 0V$		-0.88	-1.2	V
Continuous drain-source diode forward current	I_S				-35	A
Pulsed drain-source diode forward current	I_{SM}				-140	A

Notes:

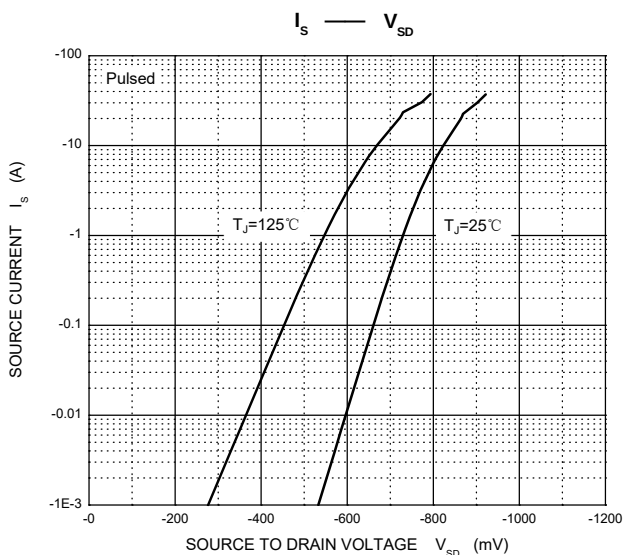
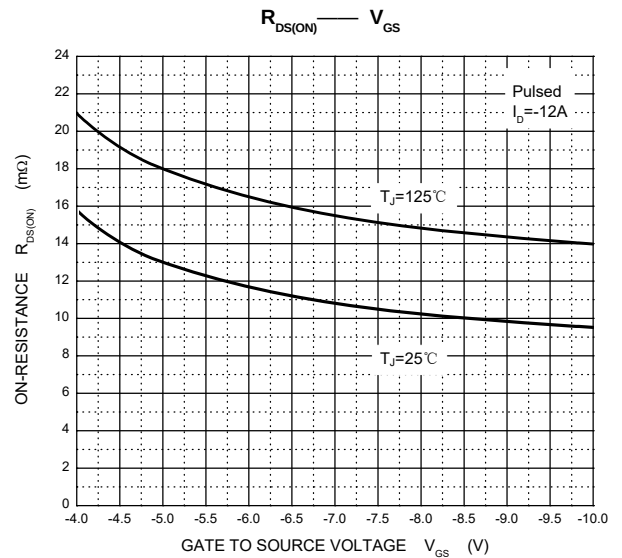
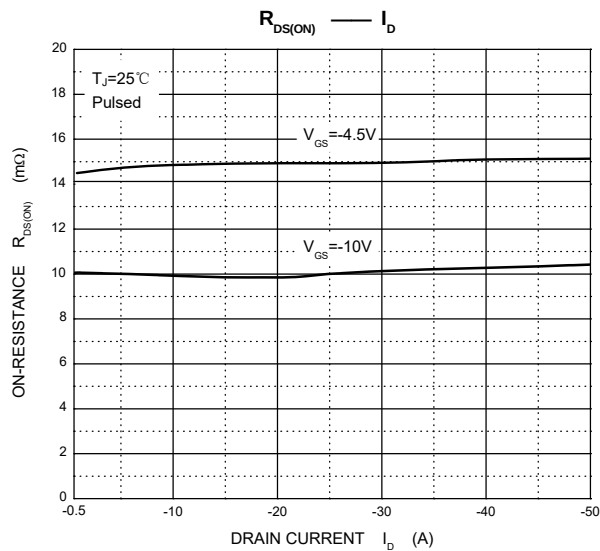
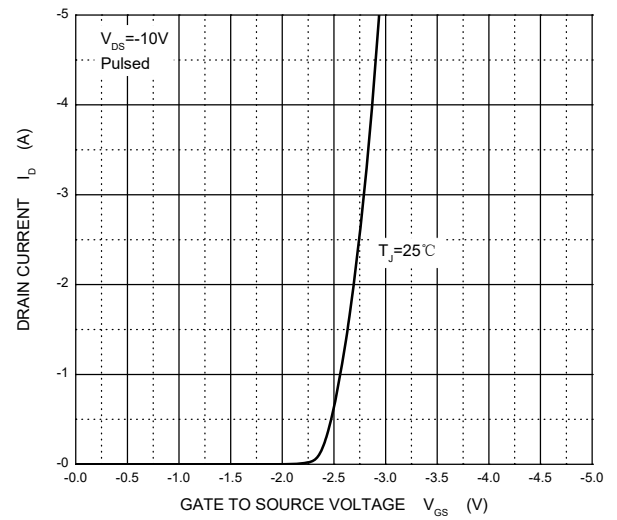
1. $T_C = 25^{\circ}\text{C}$ Limited only by maximum temperature allowed.
2. $P_W \leq 10\mu s$, Duty cycle $\leq 1\%$.
3. EAS condition: $V_{DD} = -25V, V_{GS} = -10V, L = 0.5mH, R_g = 25\Omega$ Starting $T_J = 25^{\circ}\text{C}$.
4. Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
5. Guaranteed by design, not subject to production.
6. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with $T_a = 25^{\circ}\text{C}$.

Typical Characteristics

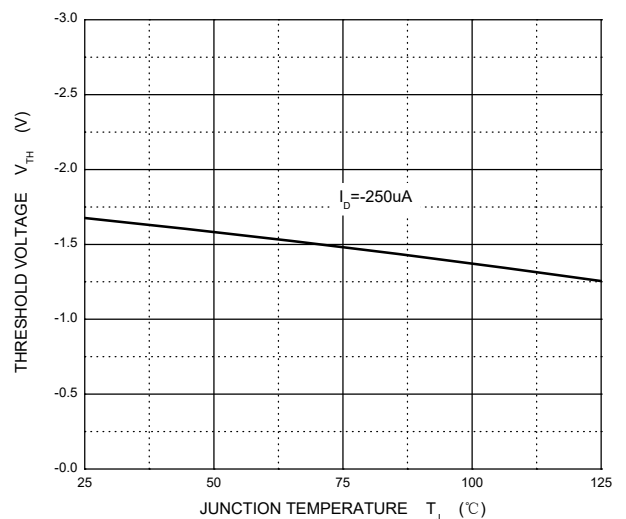
Output Characteristics



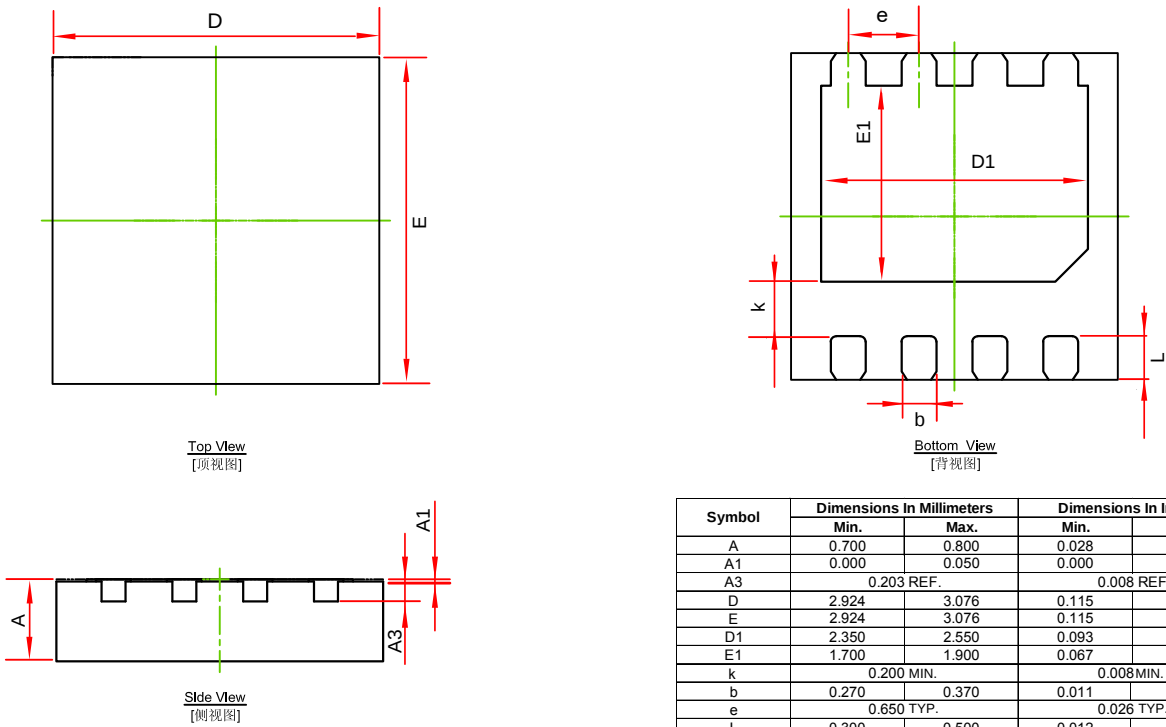
Transfer Characteristics



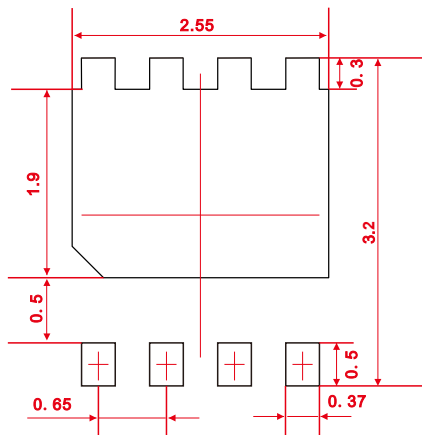
Threshold Voltage



DFNWB3×3-8L Package Outline Dimensions



DFNWB3×3-8L Suggested Pad Layout

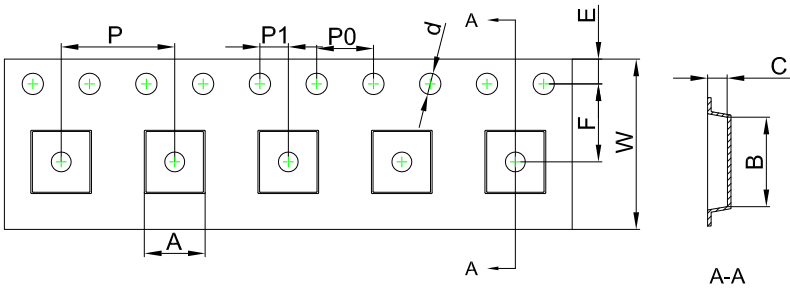


Note:
1.Controlling dimension:in millimeters.
2.General tolerance:±0.05mm.
3.The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

DFNWB3×3-8L Embossed Carrier Tape

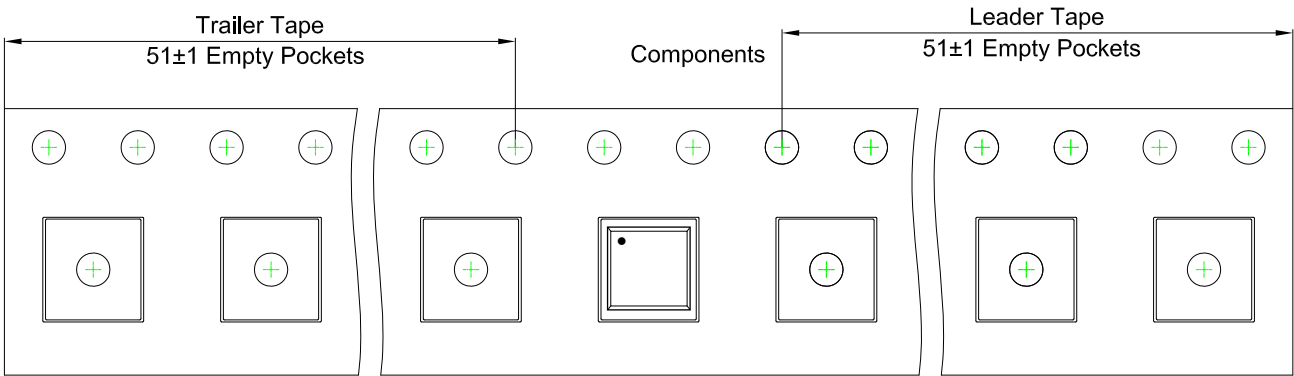


Packaging Description:

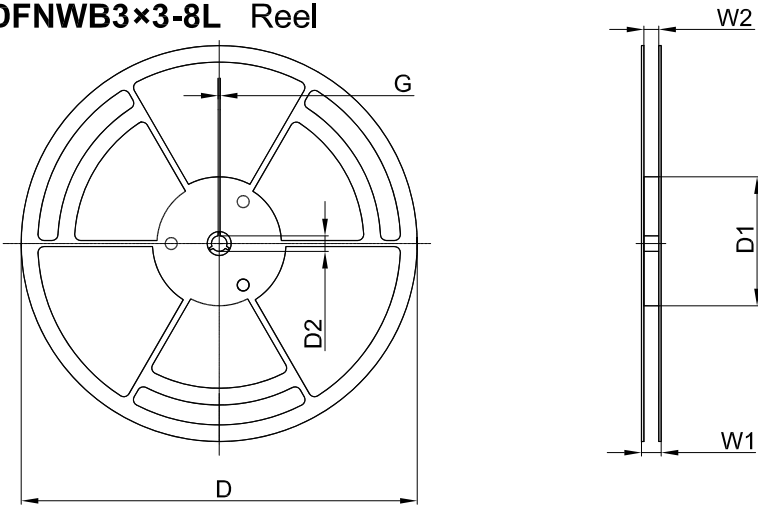
DFNWB3x3-8L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
DFNWB3×3-8L	3.35	3.35	1.13	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

DFNWB3×3-8L Tape Leader and Trailer



DFNWB3×3-8L Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	G	W1	W2
13"Dia	Ø330.00	100.00	13.00	1.90	17.60	12.40

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
5,000 pcs	13 inch	10,000 pcs	360×360×65	50,000 pcs	378×358×382